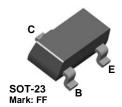


**ON Semiconductor®** 

# BCV27 NPN Darlington Transistor

### Description

This device is designed for applications requiring extremely high current gain at collector currents to 1.0 A. Sourced from process 05.



### **Ordering Information**

Part Number	Marking	Package	Packing Method
BCV27	FF	SOT-23 3L	Tape and Reel

### Absolute Maximum Ratings<sup>(1),(2)</sup>

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at  $T_A = 25^{\circ}$ C unless otherwise noted.

Symbol	Parameter	Value	Unit
V <sub>CEO</sub>	Collector-Emitter Voltage	30	V
V <sub>CBO</sub>	Collector-Base Voltage	40	V
V <sub>EBO</sub>	Emitter-Base Voltage	10	V
Ι <sub>C</sub>	Collector Current - Continuous	1.2	А
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Junction Temperature Range	-55 to +150	°C

#### Notes:

- 1. These ratings are based on a maximum junction temperature of 150  $^{\circ}\text{C}.$
- 2. These are steady-state limits. ON Semiconductor should be consulted on applications involving pulsed or lowduty-cycle operations.

### Thermal Characteristics<sup>(3)</sup>

Values are at  $T_A = 25^{\circ}C$  unless otherwise noted.

Symbol	Parameter	Max.	Unit
P <sub>D</sub>	Total Device Dissipation	350	mW
	Derate Above 25°C	2.8	mW/°C
R <sub>θJA</sub>	Thermal Resistance, Junction-to-Ambient	357	°C/W

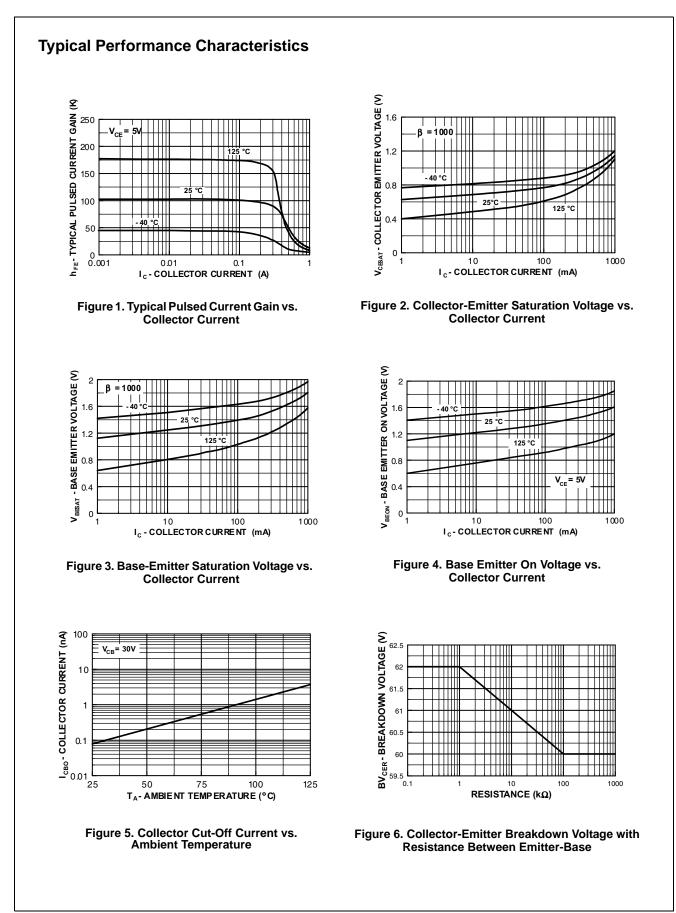
Note:

3. PCB size: FR-4, 76 mm x 114 mm x 1.57 mm (3.0 inch x 4.5 inch x 0.062 inch) with minimum land pattern size.

#### **Electrical Characteristics**

Values are at  $T_A = 25^{\circ}C$  unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 10 mA, I <sub>B</sub> = 0	30			V
V <sub>(BR)CBO</sub>	Collector-Base Breakdown Voltage	$I_{C} = 10 \ \mu A, \ I_{E} = 0$	40			V
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> = 100 nA, I <sub>C</sub> = 0	10			V
I <sub>CBO</sub>	Collector Cut-Off Current	$V_{CB} = 30 \text{ V}, I_{E} = 0$			0.1	μΑ
I <sub>EBO</sub>	Emitter Cut-Off Current	$V_{EB} = 10 \text{ V}, \text{ I}_{C} = 0$			0.1	μΑ
		$I_{C}$ = 1.0 mA, $V_{CE}$ = 5.0 V	4000			
h <sub>FE</sub>	DC Current Gain	$I_{C}$ = 10 mA, $V_{CE}$ = 5.0 V	10000			
		$I_{C}$ = 100 mA, $V_{CE}$ = 5.0 V	20000			
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 100 mA, I <sub>B</sub> = 0.1 mA			1.0	V
V <sub>BE</sub> (sat)	Base-Emitter Saturation Voltage	$I_{C} = 100 \text{ mA}, I_{B} = 0.1 \text{ mA}$			1.5	V
f <sub>T</sub>	Current Gain - Bandwidth Product	$I_{C} = 30 \text{ mA}, V_{CE} = 5.0 \text{ V},$ f = 100 MHz		220		MHz
C <sub>c</sub>	Collector Capacitance	V <sub>CB</sub> = 30 V, I <sub>E</sub> = 0, f = 1.0 MHz		3.5		pF



BCV27 — NPN Darlington Transistor

## Typical Performance Characteristics (Continued)

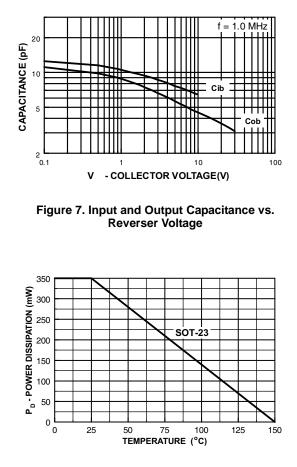


Figure 9. Power Dissipation vs. Ambient Temperature

 $f_{T}$  - GAIN BANDWIDTH PRODUCT (MHz)

500

400

300

200

100

0

<sub>ce</sub> = 5V

10 20 50 I<sub>C</sub> - COLLECTOR CURRENT (mA)

Figure 8. Gain Bandwidth Product vs. Collector Current

100 150

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